

Ultra-Fast Soft Recovery Diode Module

Description

Ultra-FRD module devices are optimized to reduce losses and EMI/RFI in high frequency power conditioning electrical systems. These diode modules are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.

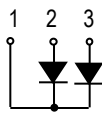
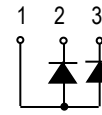
Features

- ☞ Repetitive Reverse Voltage : $V_{RRM} = 600V$
- ☞ Low Forward Voltage Drop : $V_F(\text{typ.}) = 1.5V$
- ☞ Average Forward Current : $I_F(\text{AV.}) = 150A$ @ $T_c = 100^\circ C$
- ☞ Ultra-Fast Reverse Recovery Time : $t_{rr}(\text{typ.}) = 160 \text{ ns}$
- ☞ Extensive Characterization of Recovery Parameters
- ☞ Reduced EMI and RFI
- ☞ Isolation Type Package

Applications

Motor Drives, Free wheel use, High Power Converters, Welders, Various Switching and Telecommunication Power Supply.

Equivalent Circuit and Package

Common Side & N- Type	Common Side & P-Type
	
Package : 5DM-2 Series	
	

Please see the package Out line information

Ordering Information

Device Name	DB2F150N6S	DB2F150P6S
Optional Information	Common Side & N-Type	Common Side & P-Type

Absolute Maximum Ratings @ $T_j = 25^\circ C$ (Per Leg)

Symbol	Parameter	Conditions	Ratings	Unit
V_{RRM}	Repetitive Peak Reverse Voltage		600	V
$V_{R(DC)}$	Reverse DC Voltage		480	V
$I_{F(AV)}$	Average Forward Current @ $T_c = 25^\circ C$ @ $T_c = 100^\circ C$	Resistive Load	300 150	A A
I_{FSM}	Surge(non-repetitive) Forward Current	One Half Cycle at 60Hz, Peak Value	2750	A
I^2_t	I^2t for Fusing	Value for One Cycle Current, $t_w = 8.3ms$, $T_j = 25^\circ C$ Start	35.7×10^3	A^2s
T_j	Junction Temperature		-40 ~ 150	$^\circ C$
T_{stg}	Storage Temperature		-40 ~ 125	$^\circ C$
V_{isol}	Isolation Voltage	@ AC 1 minutes	2500	V
P_d	Maximum Power Dissipation		550	W
-	Mounting Torque		4.0	N.m
-	Terminal Torque		3.0	N.m
-	Weight	Typical Including Screws	180	g

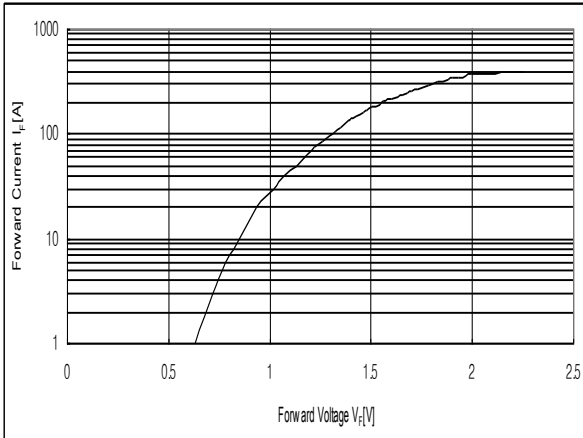
Thermal Characteristics

Symbol	Parameter	Conditions	Values			Unit
			Min.	Typ.	Max.	
$R_{th(j-c)}$	Thermal Resistance	Junction to Case	-	-	0.22	°C/W

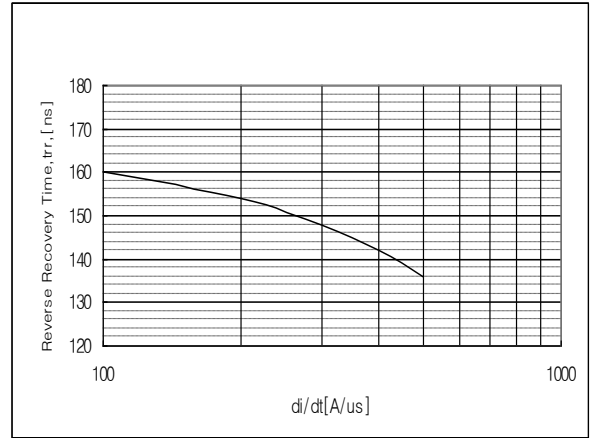
Electrical Characteristics @ $T_j=25^{\circ}\text{C}$ (unless otherwise specified)

Symbol	Parameter	Conditions	Values			Unit
			Min.	Typ.	Max.	
V_R	Cathode Anode Breakdown Voltage	$I_R = 100\mu\text{A}$	600	-	-	V
V_{FM}	Maximum Forward Voltage	$I_{FM} = 150\text{A}, T_c = 25^{\circ}\text{C}$	-	1.5	1.7	V
		$I_{FM} = 150\text{A}, T_c = 100^{\circ}\text{C}$	-	1.3	1.5	V
I_{RRM}	Repetitive Peak Reverse Current	$T_c = 100^{\circ}\text{C}, V_{RRM}$ applied	-	-	6.0	mA
T_{rr}	Reverse Recovery Time	$I_{FM} = 150\text{A}, V_R = 300\text{V}, di/dt = -100\text{A}/\mu\text{s}$ $T_c = 25^{\circ}\text{C}$	-	160	200	ns
		$T_c = 100^{\circ}\text{C}$	-	220	-	ns

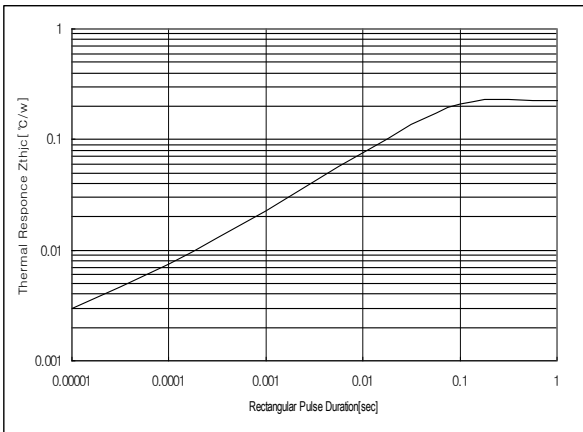
Performance Curves



**Fig. 1 : Typical Forward Voltage Drop
vs. Instantaneous Forward Current**



**Fig. 2 : Typical Reverse Recovery Time
vs. $-di/dt$**



**Fig. 3 : Transient Thermal Impedance(Z_{thjc})
Characteristics**

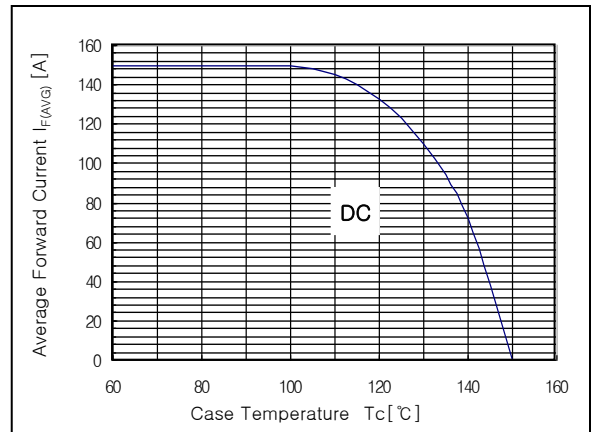


Fig. 4 : Forward Current Derating Curve

Package Out Line Information

5DM-2 Series



UNIT : mm

